Growth and Optical property of ZnO nanowire synthesized without catalyst on Si substrate

S. C. Lyu, H. J. Suh, C. J. Lee
J. S. Jeong*, J. Y. Lee*
Department of Nanotechnology, Hanyang University, Seoul 133-791, Korea
* Department of Materials Science and Engineering, KAIST, Daejeon, 306-701, Korea

Well-aligned single-crystalline wurtzite zinc oxide (ZnO) nanowire array was successfully fabricated on Si substrate by a simple physical vapor deposition method at 600°C. TEM observation showed that the ZnO nanowires were synthesized along the c-axial direction of the hexagonal crystal structure. We demonstrate that ZnO nanowires followed the self-catalyzed growth mechanism on the ZnO nuclei without metal catalyst.

We also investigate the optical property of the ZnO nanowire array by photoluminescence (PL) measurement at a room temperature.